

Content

Abstract (in Chinese).....	i
Abstract (in English).....	ii
Acknowledgements.....	iii
Contents.....	iv
List of Figures.....	vi
Chapter 1 Introduction.....	1
1.1 Introduction to nanotechnologies for one-dimensional nanostructures.....	1
1.2 Properties of ZnO and ZnO-based compounds.....	2
1.3 Motivation.....	4
1.3.1 Problems of previous growth techniques.....	4
1.3.2 Growth mechanisms and control morphology.....	4
1.4 Organization of thesis.....	5
References.....	7
Chapter 2 Theoretical background.....	9
2.1 Growth mechanism of ZnO nanostructures.....	9
2.2 Scanning Electron Microscope (SEM).....	10
2.3 X-ray diffraction.....	12
2.4 Raman scattering.....	14
2.5 Photoluminescence Characterization.....	15
2.5.1 Fundamental Transitions.....	16
2.5.2 Influence of high excited light intensity.....	18

References.....21

Chapter 3 Experiment Details.....22

3.1 Sample Preparation.....22

3.1.1 Substrate preparation.....22

3.1.2 Growth of ZnO nanostructures.....22

3.2 Structure analysis: SEM and XRD.....24

3.2.1 Scanning Electron Microscope.....24

3.2.2 X-ray diffraction.....24

3.3 Optical property: Raman and PL spectroscopies.....25

3.3.1 Raman system.....25

3.3.2 Photoluminescence (PL) system.....25

Chapter 4 Results and Discussion.....27

4.1 Structural properties of ZnO nanowires.....27

4.1.1 Growth of ZnO nanowires on -sapphire.....27

4.1.2 Structural properties and growth mechanism of ZnO nanowire.....27

4.1.3 Growth temperature dependence on structural properties of ZnO nanowire
by modified VS method.....32

4.2 Optical properties of ZnO nanowires.....36

4.2.1 Room temperature PL spectra.....36

4.2.2 Low temperature PL spectrum.....37

4.2.3 Raman spectra.....42

References.....45

Chapter 5 Conclusion and future works.....48

5.1 Conclusion.....	48
5.2 Future works.....	48

List of Figures

Fig. 1-1 Diagram of top-down and bottom-up.....	1
Fig. 1-2 Nanowires optically driven nanolaser, electrically driven nanolaser, Coaxially-gated nanowire transistors, Nano-logicgate and Nanophotonics....	2
(a) (b) Fig 1-3 ZnO wurtzite structure.....	3
Fig 1-4. ZnO structures grown at different conditions using the same gas flow and Au catalyst	5
Fig. 2-1 VLS method.....	10
Fig. 2-2 In situ TEM images recorded during the process of nanowire growth.....	10
Fig.2-3 Closed circuit TV and scanning electron microscope.....	12
Fig. 2-4 x-ray scattering from a 2-dimention periodic crystal.....	13
Fig. 2-5 The hexagonal unit cell.....	14
Fig. 2-6 Radiative transition between a band and an impurity state.....	18
Fig. 2-7 The general scenario for many-particle effects in semiconductors.....	19
Fig.2-8 Schematic representation of the inelastic exciton-exciton scattering processes.....	20
Fig. 3-1 Thermal vapor transport system.....	23
Fig. 3-2 FESEM system.....	24
Fig. 3-3 Raman system.....	25
Fig. 3-4 The PL system.....	26
Fig. 4-1 The oblique and cross section views of SEM images of ZnO nanowires grown by the modified VS and the conventional VS methods.....	29
Fig. 4-2 The XRD pattern of ZnO nanowires produced by the conventional VS	

method and the modified VS method.....	30
Fig. 4-3 The top view of ZnO film, top view, cross-sectional images and side view of ZnO nanowire are fabricated from modified VS method at different temperature.....	33
Fig. 4-4 The XRD pattern of ZnO depend on different growth temperature on a plane sapphire substrate.....	34
Fig. 4-5 The SEM cross-section image of ZnO nanowire at 520	35
Fig. 4-6 A schematic shows the angular relationship between the m-plane and a-plane sapphire.....	36
Fig. 4-7 The PL spectra of the ZnO nanowire at room temperature.....	37
Fig. 4-8 The low temperature PL spectra of samples grown with the same conditions by using modified VS method and conventional VS method.....	39
Fig. 4-9 PL overview spectrum of ZnO sample recorded at 13K.....	41
Fig. 4-10 Series of low temperature PL spectra of the ZnO sample recorded at different temperature.....	41
Fig. 4-11 The integral PL intensity PL intensity in the UV region.....	42
Fig. 4-12 micro-Raman spectra of the ZnO nanowires were grown on sapphire substrate at different temperature.....	44